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# Rigorous retrieval of linear and nonlinear parameters in graphene waveguides

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## Presentation Outline

- **Framework**
  - Nonlinear propagation in graphene waveguides
  - Motivation & objectives
- **Electromagnetic modelling**
  - Graphene as a conductive sheet
  - Equivalent bulk medium representation
  - FEM formulation considering graphene as a sheet
  - Nonlinear waveguide parameters and the NLSE
- **Review of graphene physical properties**
  - Linear conductivity
  - Nonlinear conductivity
- **Nonlinear parameter calculation**
  - Optical frequencies
  - Terahertz
- **To probe further**

# Framework

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## Framework / Nonlinear propagation in graphene waveguides

- ❖ Strong recent interest in **nonlinear propagation effects** in graphene but with some skepticism, as well.

Hendry *et al.*, *Coherent Nonlinear Optical Response of Graphene*, PRL, 2010

Gu *et al.*, *Regenerative oscillation and four-wave mixing in graphene optoelectronics*, Nat Photonics, 2012

Gorbach, *Nonlinear graphene plasmonics: Amplitude equation for surface plasmons*, PRA, 2013

Ooi *et al.*, *Waveguide engineering of graphene's nonlinearity*, APL, 2014

Khurgin, *Graphene—A rather ordinary nonlinear optical material*, APL, 2014

- ❖ Various publications report **high (giant?) nonlinearity** levels in graphene.
- ❖ Theoretical frameworks still not well developed and lacking the understanding of nonlinear effects in photonics.
- ❖ Rather **poor correlation** between theoretical and experimental results and very few device-oriented experiments.
- ❖ So, is there any **exploitable potential** in nonlinear graphene waveguides?

## Framework / Motivation & objectives

❖ Current literature in nonlinear graphene waveguides include various **simplifications and misconceptions** related to:

- inappropriate effective medium representations
- inconsistent introduction of graphene tensorial properties
- superficial or excessive models for graphene's nonlinearity
- poor waveguide engineering

❖ Our **objectives** include:

- treatment of graphene as sheet (2D material)
- full/complete tensorial representation of nonlinear surface conductivity
- rigorous calculation of nonlinear parameter  $\gamma$  ( $\text{W}^{-1}\text{m}^{-1}$ ) for arbitrary waveguide cross-sections (Kerr response)
- quantify individual sheet and bulk nonlinear contributions in  $\gamma$  for a range of waveguide archetypes
- engineer the waveguide cross-section to enhance  $\gamma$

# Electromagnetic Modelling

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# Electromagnetic Modelling / Graphene as a conducting sheet

Maxwell's curl equations, including both linear and nonlinear contributions:

$$\begin{aligned}\nabla \times \tilde{\mathbf{E}} &= +i\omega\mu_0\bar{\mu}_r\tilde{\mathbf{H}} & \tilde{\mathbf{J}} &= \tilde{\mathbf{J}}_{\text{lin}} + \tilde{\mathbf{J}}_{\text{NL}}, \quad \tilde{\mathbf{J}}_{\text{NL}} \ll \tilde{\mathbf{J}}_{\text{lin}} = \sigma_s^{(1)}\tilde{\mathbf{E}} \\ \nabla \times \tilde{\mathbf{H}} &= -i\omega(\varepsilon_0\tilde{\mathbf{E}} + \tilde{\mathbf{P}}) + \tilde{\mathbf{J}} & \tilde{\mathbf{P}} &= \tilde{\mathbf{P}}_{\text{lin}} + \tilde{\mathbf{P}}_{\text{NL}}, \quad \tilde{\mathbf{P}}_{\text{NL}} \ll \tilde{\mathbf{P}}_{\text{lin}} = \varepsilon_0\bar{\chi}^{(1)}\tilde{\mathbf{E}}\end{aligned}$$

perturbation

Bulk current density, expanded similarly to polarization  $\mathbf{P}$ :

$$\mathbf{J}_b = \bar{\sigma}^{(1)} | \mathbf{E} + \bar{\sigma}^{(2)} | \mathbf{E}\mathbf{E} + \bar{\sigma}^{(3)} | \mathbf{E}\mathbf{E}\mathbf{E} + \dots$$

Surface current density on graphene:

$$\mathbf{J}_s = \bar{\sigma}_s^{(1)} | \mathbf{E} + \bar{\sigma}_s^{(2)} | \mathbf{E}\mathbf{E} + \bar{\sigma}_s^{(3)} | \mathbf{E}\mathbf{E}\mathbf{E} + \dots$$

important

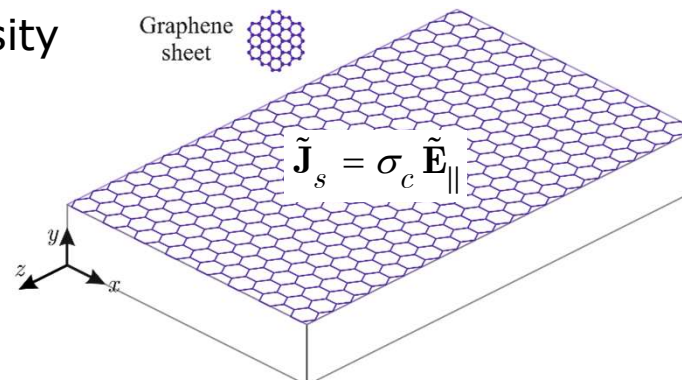
important

$\bar{\sigma}_s^{(n)}$

 Surface conductivity tensor, rank (n+1), in  $[\text{S(m/V)}^{n-1}]$ 

Overall current density

$$\mathbf{J} = \mathbf{J}_b + \mathbf{J}_s\delta_s(\mathbf{r})$$



$$\bar{\sigma}_s^{(1)} = \begin{bmatrix} \sigma_{s,xx} & 0 & \sigma_{s,xz} \\ 0 & 0 & 0 \\ \sigma_{s,zx} & 0 & \sigma_{s,zz} \end{bmatrix}$$

$$\sigma_{s,xx} = \sigma_{s,zz} \equiv \sigma_c, \sigma_{s,xz} = \sigma_{s,zx} \approx 0$$

# Electromagnetic Modelling / Graphene as a conducting sheet

We focus on **self-acting third-order nonlinear effects**, i.e. **Kerr effect** and **TPA**:

$$J_{s,j,NL} = \mathbf{J}_{s,NL} \cdot \mathbf{j} = \frac{3}{4} \sum_{klm} \sigma_{s,jklm}^{(3)} E_k E_l^* E_m$$

j-th Cartesian of the nonlinear surface current

$\bar{\sigma}_s^{(3)}$  Surface conductivity tensor, 4<sup>th</sup>-rank (81 elements),  
units [S(m/V)<sup>2</sup>]

- Hexagonal symmetry group
  - Normal to sheet component of  $\mathbf{J}_{s,NL}$  vanishes
- Up to **14 non-zero** elements & up to **6** are **independent!**

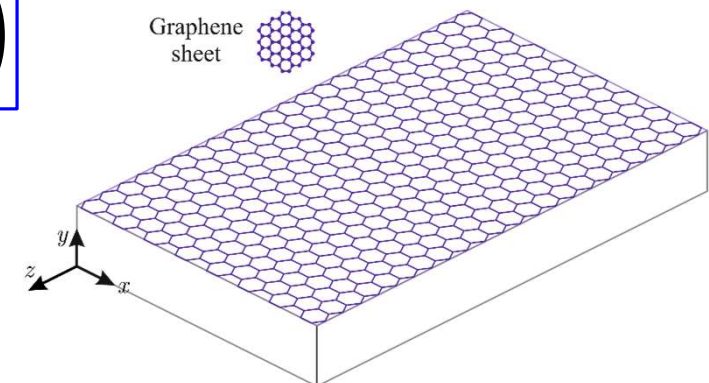
**Simplest form** (8 non-zero, 1 independent), i.e. 2D-equivalent of an isotropic bulk (3D) medium:

$$\sigma_{s,jklm}^{(3)} = \sigma_3 \frac{1}{3} \left( \delta_{jk} \delta_{lm} + \delta_{jm} \delta_{kl} + \delta_{jl} \delta_{mk} \right)$$

For example, a graphene sheet normal to the y-axis

$$\sigma_{s,xxxx}^{(3)} = \sigma_{s,zzzz}^{(3)} = \sigma_3$$

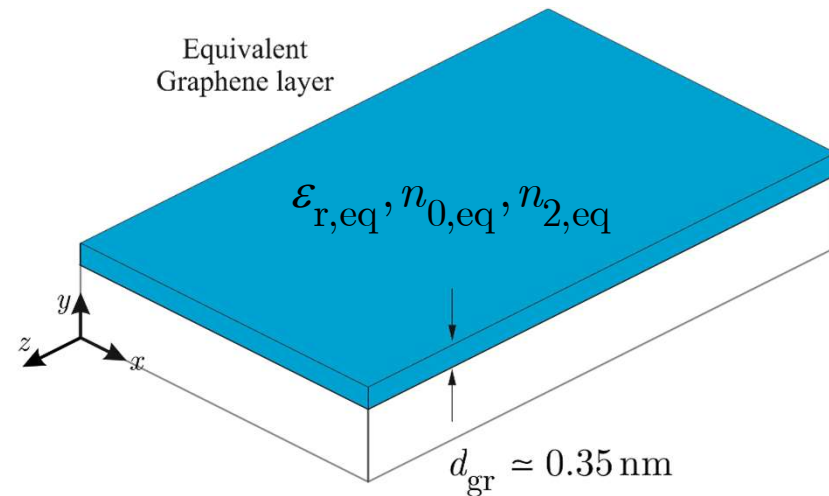
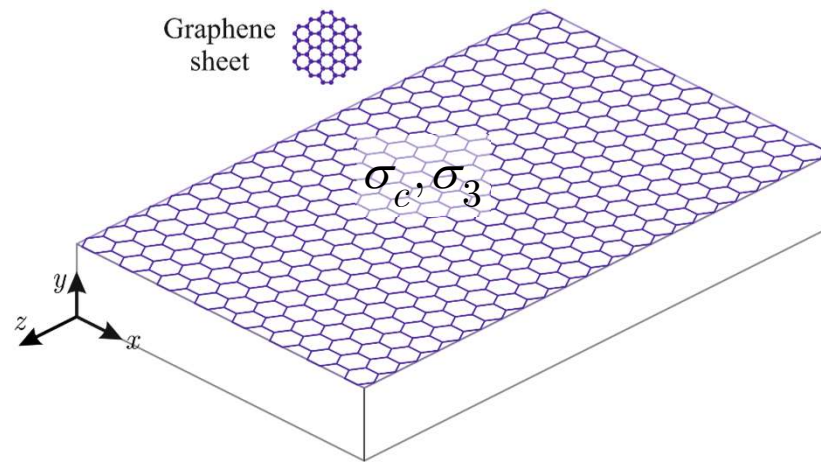
$$\sigma_{s,mmnn}^{(3)} = \sigma_{s,mnnm}^{(3)} = \sigma_{s,mnmm}^{(3)} = \frac{1}{3} \sigma_3 \quad \{m, n\} = \{x, z\}$$





# Electromagnetic Modelling / Equivalent bulk medium representation

Widespread choice, but commonly leads to poor or misleading results!



Equivalent bulk medium pros & cons:

- very simple approach
- allows usage of existing SW tools
- introduces an artificial thickness
- excessive computational burden
- tensorial information easily lost

$$\text{map } \epsilon_{r,\text{eq}} \rightarrow \bar{\epsilon}_{r,\text{eq}}$$

$$\bar{\chi}_{\text{eq}}^{(m)} = i\bar{\sigma}_s^{(m)} / (\omega\epsilon_0 d_{\text{gr}})$$

$$\epsilon_{r,\text{eq}} = n_{0,\text{eq}}^2 = 1 + \chi_{\text{eq}}^{(1)} = 1 + \frac{i\sigma_c}{\omega\epsilon_0 d_{\text{gr}}}$$

$$n_{2,\text{eq}} = \frac{3}{4} \frac{\chi_{\text{eq}}^{(3)}}{\epsilon_{r,\text{eq}}} Z_0 = \frac{3}{4} \times \frac{i\sigma_3 / (\omega\epsilon_0 d_{\text{gr}})}{1 + i\sigma_c / (\omega\epsilon_0 d_{\text{gr}})} Z_0$$

# Electromagnetic Modelling / FEM formulation considering graphene as a sheet

Finite Element Method is used to analyze the **linear** problem. Graphene is rigorously introduced as **sheet** (zero thickness) characterized by **surface** conductivity tensors.

$$\begin{aligned} \mathbf{n} \times (\tilde{\mathbf{E}}_2 - \tilde{\mathbf{E}}_1) &= \mathbf{0} \\ \mathbf{n} \times (\tilde{\mathbf{H}}_2 - \tilde{\mathbf{H}}_1) &= \tilde{\mathbf{J}}_s \end{aligned} \quad \text{Boundary Conditions}$$

Usual Galerkin procedure:

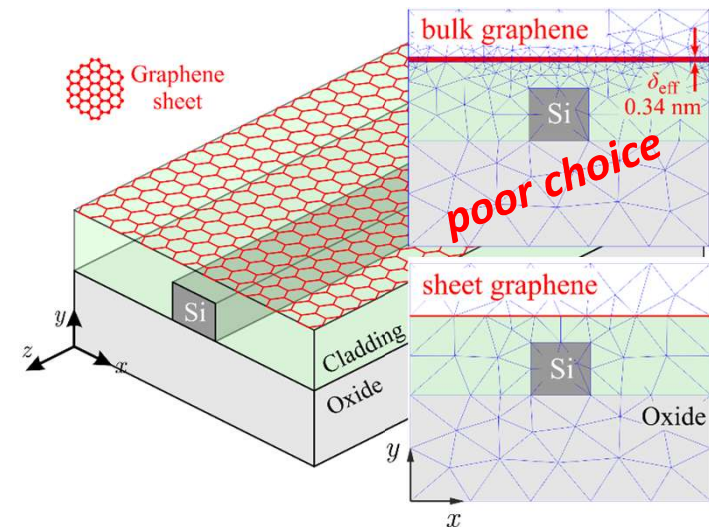
LHS → Standard FEM bulk term

$$\iiint_V \left\{ (\nabla \times \tilde{\mathbf{E}}_a) \cdot [\mu_r^{-1} (\nabla \times \tilde{\mathbf{E}})] - k_0^2 \tilde{\mathbf{E}}_a \cdot [\bar{\epsilon}_r \tilde{\mathbf{E}}] \right\} dV = i\omega\mu_0 \iint_S \tilde{\mathbf{E}}_a \cdot [\bar{\sigma}_s^{(1)} \tilde{\mathbf{E}}] dS$$

In the simplest case:  $\bar{\sigma}_s^{(1)} \tilde{\mathbf{E}} = \sigma_c \tilde{\mathbf{E}}_{\parallel} = \sigma_c [\mathbf{n} \times (\tilde{\mathbf{E}} \times \mathbf{n})]$

RHS → Graphene surface term

$$\text{RHS} \quad \iint_S \tilde{\mathbf{E}}_a \cdot [\bar{\sigma}_s^{(1)} \tilde{\mathbf{E}}] dS = \sigma_c \iint_S (\mathbf{n} \times \tilde{\mathbf{E}}_a) \cdot (\mathbf{n} \times \tilde{\mathbf{E}}) dS$$



# Electromagnetic Modelling / Nonlinear waveguide parameters and the NLSE

Nonlinear Schrodinger Equation (NLSE) framework for Kerr & TPA: extract the nonlinear parameter  $\gamma_{\text{NL}}$  (mW)<sup>-1</sup>, that quantifies nonlinear phase shift or loss.

Basic Figure of Merit  $\mathcal{F} = \gamma_{\text{NL}} L_{\text{prop}} \quad (1/\text{W})$

$$\nabla \times \tilde{\mathbf{H}} = -i\omega\epsilon_0 \left( \bar{\epsilon}_{\text{r}} - \frac{\bar{\sigma}^{(1)}}{i\omega\epsilon_0} \right) \tilde{\mathbf{E}} - i\omega \underbrace{\left( \tilde{\mathbf{P}}_{\text{NL}} + \frac{i}{\omega} \tilde{\mathbf{J}}_{\text{NL}} \right)}_{\text{Overall perturbation term } \tilde{\mathbf{P}}'_{\text{NL}} = \tilde{\mathbf{P}}_{\text{NL}} + i\omega^{-1} \tilde{\mathbf{J}}_{\text{NL}}}$$

Vector NLSE (Afshar & Monroe, OPEX, 2009), (Daniel & Agrawal, JOSA B, 2010):

$$\tilde{\mathbf{E}}(\mathbf{r}, \omega) = \tilde{A}(z, \omega - \omega_0) \mathbf{e}(x, y, \omega_0) \exp(+i\beta_0 z) / \sqrt{N}$$

Time-domain nonlinear  
propagation equation  
for SVE

$$\frac{\partial A}{\partial z} = \frac{i\omega_0 e^{i(\omega_0 t - \beta_0 z)}}{2\sqrt{4N}} \iint \mathbf{e}^* \cdot \left( \mathbf{P}_{\text{NL}} + \frac{i}{\omega_0} \mathbf{J}_{\text{NL}} \right) dS + \mathcal{L}A$$

Linear operator  $\mathcal{L}$  : dispersion + losses

# Electromagnetic Modelling / Nonlinear waveguide parameters and the NLSE

$$P_{j,\text{NL}} = \mathbf{P}_{\text{NL}} \cdot \mathbf{j} = \frac{3\epsilon_0}{4} \sum_{klm} \chi_{jklm}^{(3)} E_k E_l^* E_m$$

$$J_{s,j,\text{NL}} = \mathbf{J}_{s,\text{NL}} \cdot \mathbf{j} = \frac{3}{4} \sum_{klm} \sigma_{s,jklm}^{(3)} E_k E_l^* E_m$$

We substitute in the time-domain  
nonlinear equation for the SVE

**Nonlinear Schrodinger Equation**  
(here simply written for CW)

$$\frac{\partial A}{\partial z} = -\frac{1}{2L_{\text{prop}}} A + i(\gamma_b + \gamma_s) |A|^2 A$$

**Bulk nonlinearity**

**Sheet (graphene) nonlinearity**

$$\gamma_b = \frac{3\omega_0\epsilon_0}{4(2N)^2} \sum_{jklm}^{xyz} \iint \chi_{jklm}^{(3)} e_j^* e_k^* e_l^* e_m dS$$

$$\gamma_s = i \frac{3}{4(2N)^2} \sum_{jklm}^{xyz} \int \sigma_{s,jklm}^{(3)} e_j^* e_k^* e_l^* e_m d\ell$$

Simplest possible, yet rigorous, expressions

$$\gamma_b = \frac{\omega_0\epsilon_0}{(2N)^2} \iint \chi_3 \left( \frac{1}{2} |\mathbf{e}|^4 + \frac{1}{4} |\mathbf{e} \cdot \mathbf{e}|^2 \right) dS$$

$$\gamma_s = i \frac{1}{(2N)^2} \int \sigma_3 \left( \frac{1}{2} |\mathbf{e}_{\parallel}|^4 + \frac{1}{4} |\mathbf{e}_{\parallel} \cdot \mathbf{e}_{\parallel}|^2 \right) d\ell$$

# Review of graphene physical properties

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# Review of graphene physical properties / Linear conductivity

Overall linear surface conductivity

$$\sigma_c = \sigma_{c,\text{intra}} + \sigma_{c,\text{inter}}$$

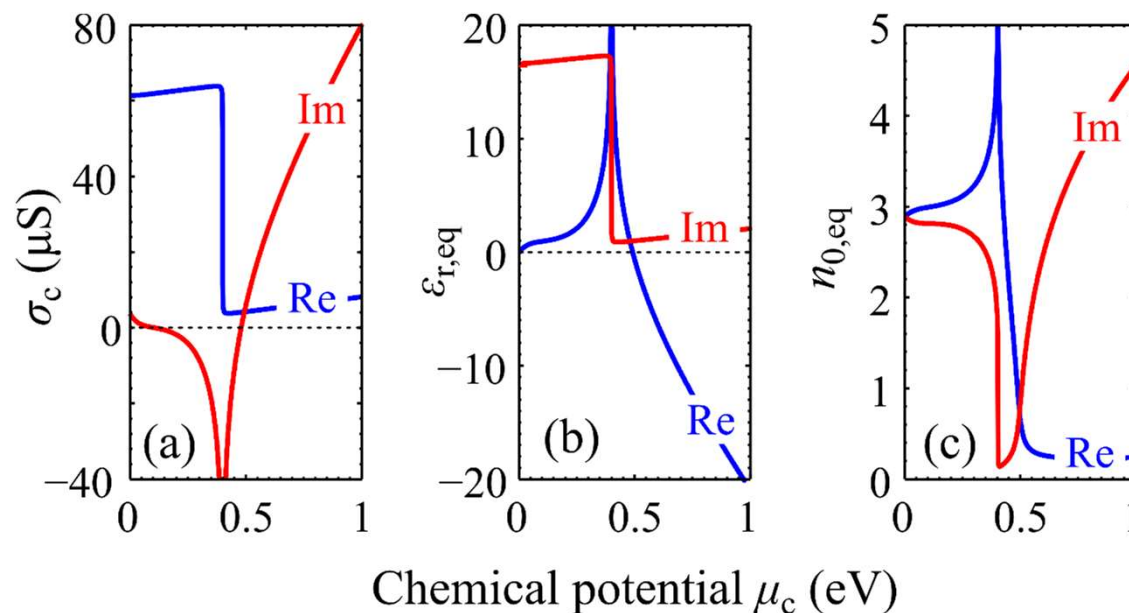
Simplest scalar form of  $\bar{\sigma}_s^{(1)}$

$$\sigma_{c,\text{intra}} = i \frac{e^2 \mu_c}{\pi \hbar^2 (\omega + i / \tau_1)} \times \mathcal{T} \left( \frac{\mu_c}{2k_B T} \right)$$

**Intraband contribution**  
(Drude)

$$\sigma_{c,\text{inter}} = i \frac{e^2}{4\pi \hbar} \ln \left[ \frac{2 |\mu_c| - \hbar(\omega + i / \tau_2)}{2 |\mu_c| + \hbar(\omega + i / \tau_2)} \right]$$

**Interband contribution**  
(unimportant at THz)  
Disappears when  $\mu_c > \hbar \omega / 2$



Re & Im part of graphene surface conductivity, equivalent  $\epsilon_r$  and equivalent (linear) refractive index  $n_0$  at 1550 nm.

# Review of graphene physical properties / Nonlinear conductivity

Nonlinear graphene surface conductivity: a topic of much debate!

Simplest possible form  
of 4<sup>th</sup>-rank tensor  $\bar{\sigma}_s^{(3)}$ :

$$\sigma_{s,jklm}^{(3)} = \sigma_3 \frac{1}{3} (\delta_{jk} \delta_{lm} + \delta_{jm} \delta_{kl} + \delta_{jl} \delta_{mk})$$

$$\sigma_{3,\text{opt}} \approx -i10^{-23} [\text{S(m / V)}^2] @ 1550 \text{ nm}$$

Hendry *et al.*, PRL, 2010

$$\sigma_{3,\text{opt}} = -i \frac{9e^4 v_F^2}{32 \omega^4 \hbar^3}$$

$$v_F \approx c_0 / 300$$

$$\sigma_{3,\text{THz}} \approx -i10^{-19} [\text{S(m / V)}^2] @ 10 \text{ THz}$$

Mikhailov & Ziegler,

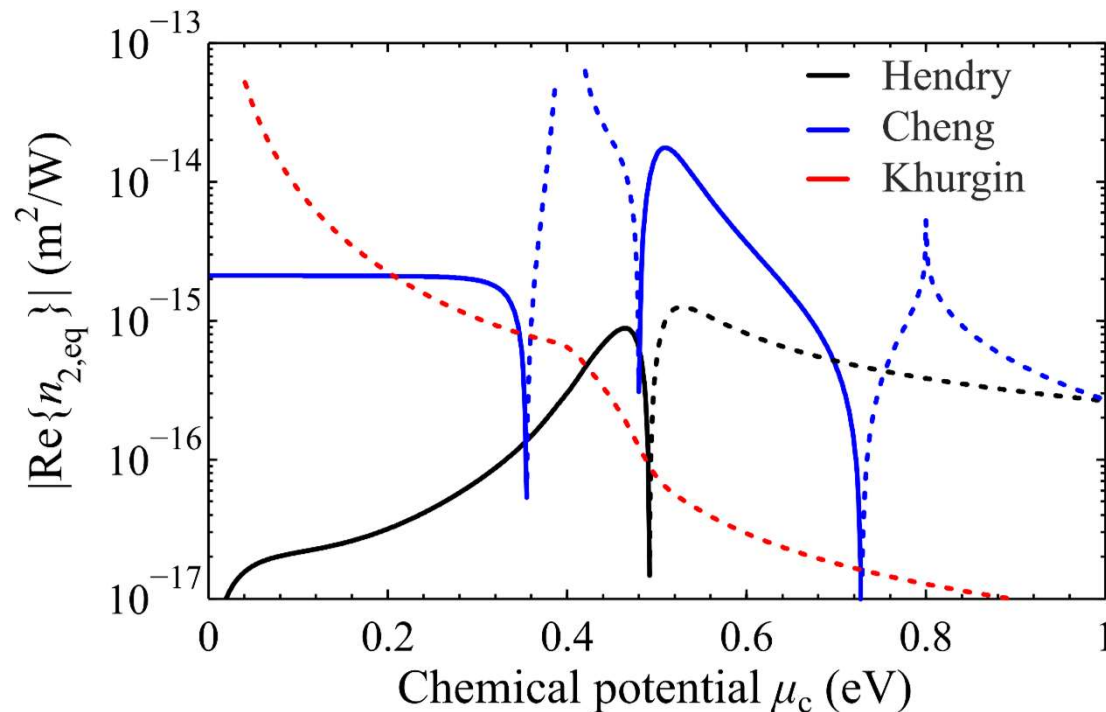
J. Phys.: Condens. Matter, 2008

$$\sigma_{3,\text{THz}} = -i \frac{3e^4 v_F^2}{32 \omega^3 \hbar^2 \mu_c}$$

**Number of elements in graphene's nonlinear surface conductivity tensor  $\bar{\sigma}_s^{(3)}$**

Source	Non-zero	Independent
Hexagonal 2D crystal	8+6	3+3
Gorbach <i>et al.</i> , OL, 2013	8+6	1+1
Cheng <i>et al.</i> , New J. Phys, 2014	8	2
Simplest model	8	1

## Review of graphene physical properties / Nonlinear conductivity



Absolute value of  $\text{Re}\{n_{2,\text{eq}}\}$ .  
Solid (positive),  
Dashed (negative).

Equivalent nonlinear index  $n_2$  undergoes **sign transitions** at  $|\text{Re}\{n_{0,\text{eq}}\}| = |\text{Im}\{n_{0,\text{eq}}\}|$

Index  $n_2$  can be in the range of  **$10^{-15} \text{ m}^2/\text{W}$** . For comparison, Si  $\sim 2.5 \times 10^{-18} \text{ m}^2/\text{W}$ , Chalcogenides  $\sim 10^{-17} \text{ m}^2/\text{W}$ , polymers (DDMEBT)  $\sim 1.7 \times 10^{-17} \text{ m}^2/\text{W}$ .

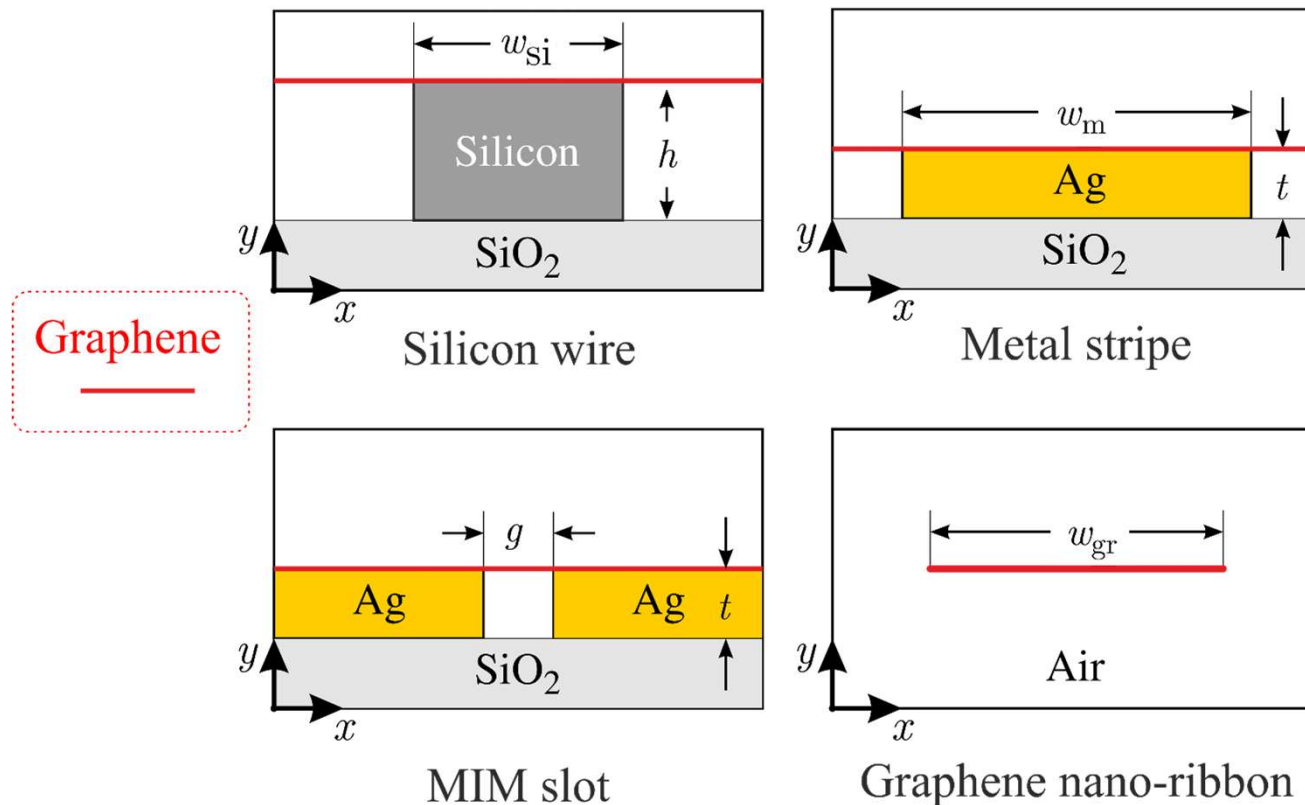
However, without the right waveguide engineering, this high value does **not** translate into a high  $\gamma_{\text{NL}}$  parameter.



# Nonlinear parameter calculation

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# Nonlinear parameter calculation / Optical frequencies



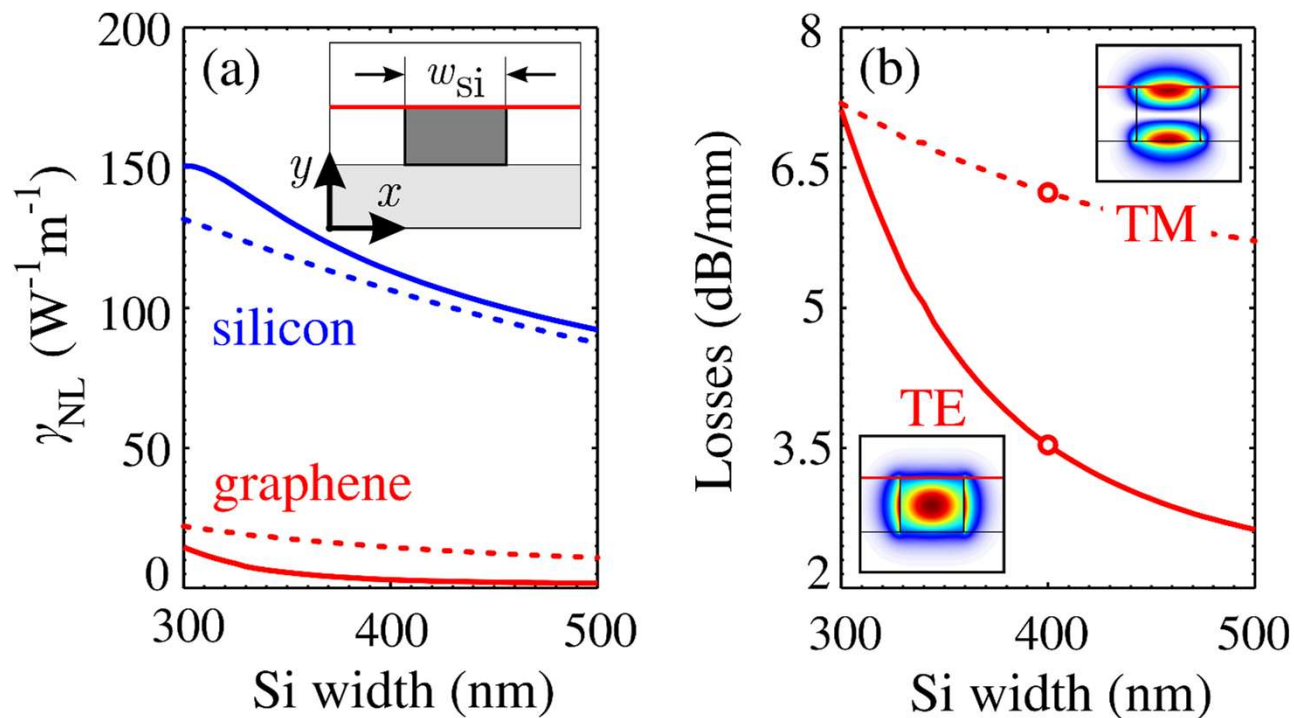
Here shown simple/trivial layouts of graphene, but our formulation allows for:

- Inhomogeneous  $\sigma_1$  &  $\sigma_3$
- arbitrary orientations (curved, etc.)
- multiple sheets

- We will assess how the presence of a graphene layer affects the nonlinearity of “standard” photonic and plasmonic waveguides.

## Nonlinear parameter calculation / Optical frequencies

## Silicon wire overlaid with graphene



Insets:

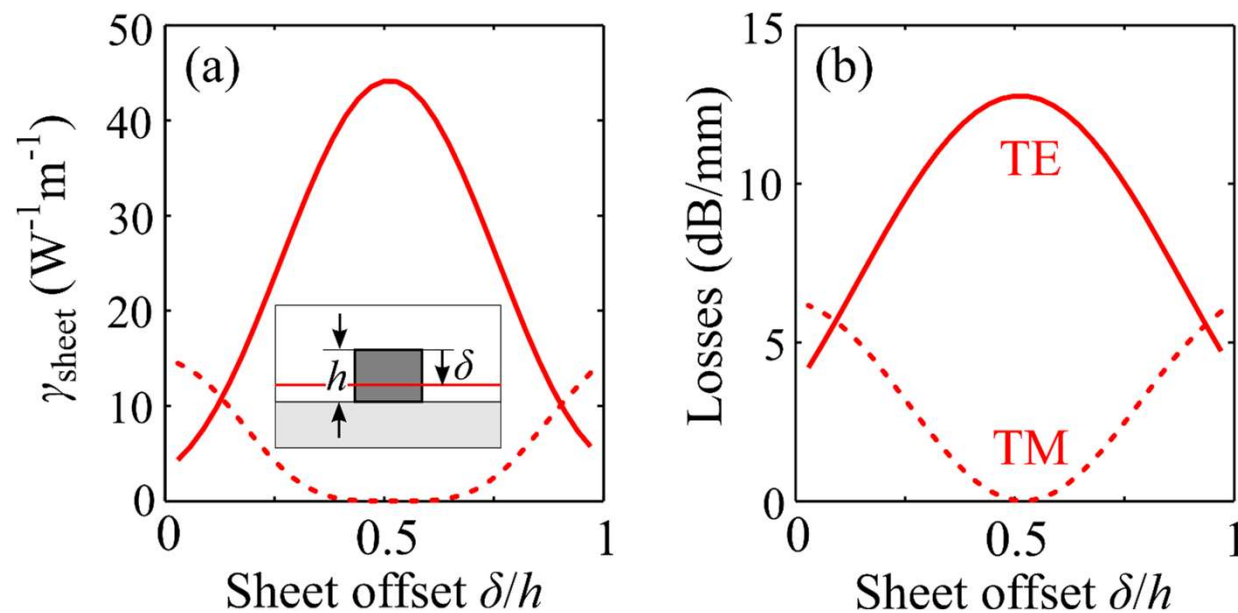
$$|e_x|^2 + |e_z|^2$$

$$\mu_c = 0.5 \text{ eV}$$

- Graphene nonlinearity is much **lower compared** to that of bulk Si.
- **Marginal interaction** of w/g mode with graphene.
- Counterintuitively,  $\gamma_{gr}$  is **larger for TM modes**, partially due to  $E_z$ !
- **Losses are too high** (they reduce from ~1 dB/cm to ~5 dB/mm).

## Nonlinear parameter calculation / Optical frequencies

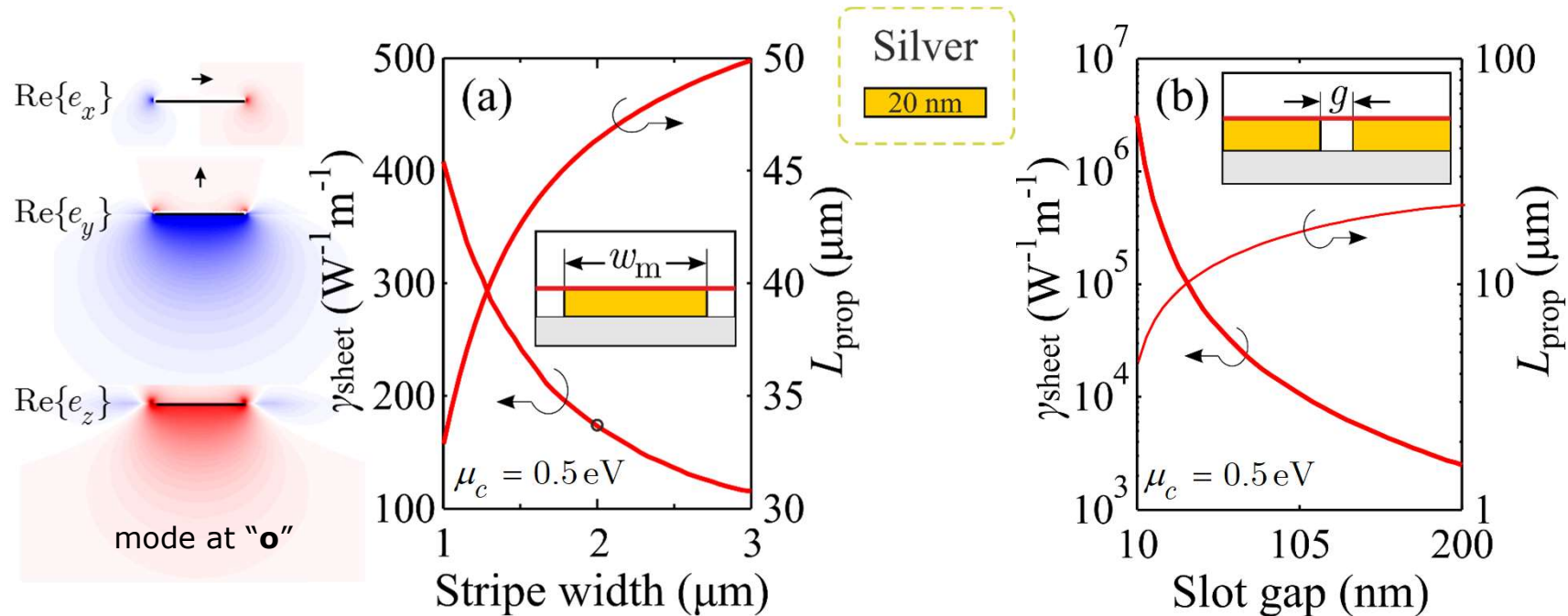
Can we enhance graphene's contribution in the Si-wire waveguide?



- Graphene sheet **artificially offset** through the Si-core.
- Sheet nonlinearity is **now comparable** to that of bulk Si ( $\sim 110 \text{ W}^{-1}\text{m}^{-1}$ ).
- **May not be easy** to fabricate.
- **Still higher losses.**

# Nonlinear parameter calculation / Optical frequencies

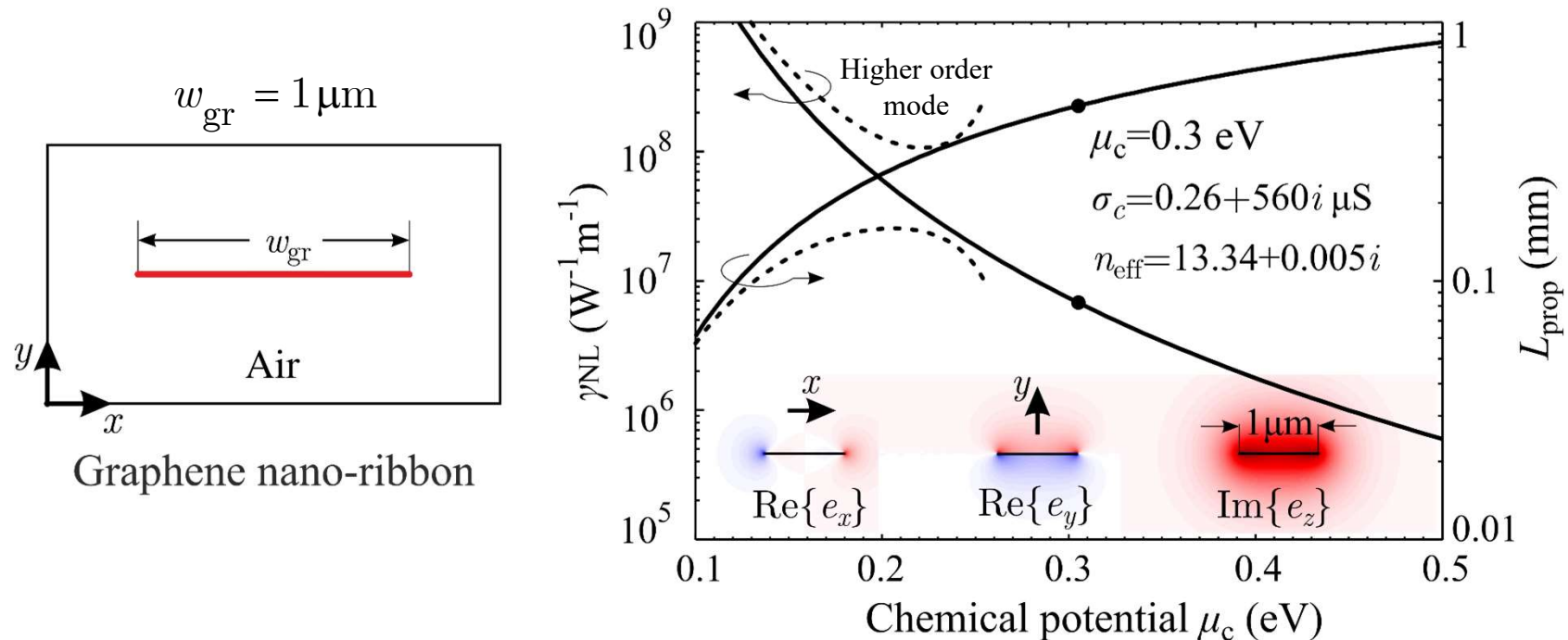
## Plasmonic waveguides: metal stripe & MIM slot



- We exploit the **y-antisymmetric mode** and not the symmetric "long-range".
- $\gamma_{\text{sheet}}$  **exceeds Si** contribution.
- $\gamma_{\text{sheet}}$  **improves** by reducing thickness.
- **Metal loss dominates.**
- TE polarization ensures **strong interaction**. High field confinement.
- $\gamma_{\text{sheet}}$  **orders of magnitude above Si**.
- $\gamma_{\text{sheet}}$  **improves** by reducing thickness.
- For small gaps **metal & graphene equally contribute** to losses.

## Nonlinear parameter calculation / Terahertz

## THz: Graphene Nano-Ribbon (GNR)



- Nonlinear parameter  $\gamma_{\text{NL}}$  **is excessive**.
- The "edge" plasmonic mode provides **highly confined field components**.
- Propagation length  $\sim 10\lambda$  at 10 THz.
- **Ample tuning** via chemical potential (gating), as  $\sigma_3$  depends on  $\mu_c$ .

## To probe further

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## To probe further

### ❖ Current work:

- **rigorous derivation** of the nonlinear parameter  $\gamma$
- **full tensorial properties** retained
- **MIM** slots overlaid with graphene lead to ultra-high  $\gamma$  at tolerable losses
- **higher nonlinearity** is always associated with increasing **losses**
- more promising results provided by **graphene nano-ribbons at THz**

### ❖ Future work:

- better understanding of the most **appropriate** surface conductivity model
- include **more nonlinear effects**:
  - Two Photon Absorption (trivial)
  - Carrier Effects, FCD & FCA
  - Four Wave Mixing
- more **complex graphene layouts** (bilayers, etc.) or biasing conditions
- more efficient **waveguide engineering**



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